

AP3968/69/70/70S

General Description

The AP3968/69/70/70S consists of a primary side regulation controller and a high voltage transistor, and is specially designed for off-line power supplies within 12W output power. Typical applications include adapter for ADSL and auxiliary supplies.

The AP3968/69/70/70S operates at pulse frequency modulation (PFM), and provides accurate constant voltage, constant current (CV/CC) regulation without requiring an opto-coupler and secondary control circuitry. It has internal cable compensation function for tight constant voltage regulation.

The AP3968/69/70/70S solution has fewer component numbers, smaller size, and lower total cost.

The AP3968 is packaged in SOIC-7. The AP3969/70/70S is packaged in DIP-7 and DIP-8.

Features

- Primary Side Control for Eliminating Opto-coupler and Secondary CV/CC Control Circuitry
- Built-in NPN Transistor with 700V_{CBO}
- Low Start-up Current: 0.2μA (Typ.)
- Internal Output Cable Voltage Drop Compensation
- Random Frequency Modulation for Low EMI
- Short Circuit Protection
- Low Total Cost Solution
- Output Power Range (Note 1): AP3968 for 5W Adapter AP3969 for 7.5W Adapter AP3970 for 12W Adapter AP3970S for 10W Adapter

Note 1: Typical continuous power in a non-ventilated enclosed adapter measured at 50°C ambient.

Applications

- Chargers
- Adapters
- Set Top Boxes
- Auxiliary Supplies
- DVD
- LED Driver

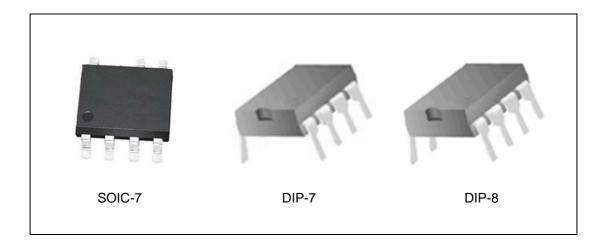
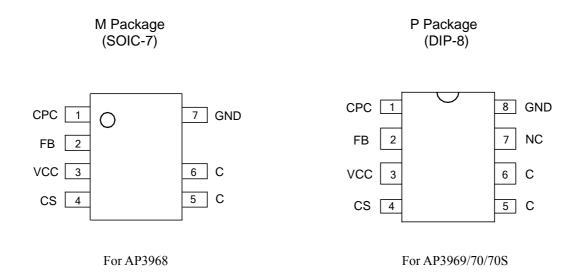


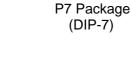
Figure 1. Package Types of AP3968/69/70/70S

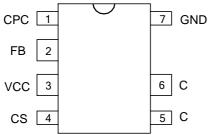


AP3968/69/70/70S

Pin Configuration







For AP3969/70/70S

Figure 2. Pin Configuration of AP3968/69/70/70S (Top View)



AP3968/69/70/70S

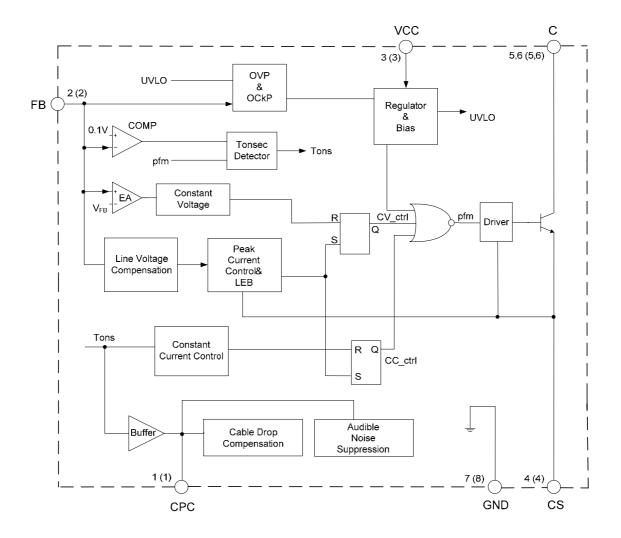
Pin Description

| Pin Number | | Din Nome | E | | |
|--------------|-------|----------|---|--|--|
| SOIC-7/DIP-7 | DIP-8 | Pin Name | Function | | |
| 1 | 1 | СРС | This pin connects a capacitor to GND for output cable compensation | | |
| 2 | 2 | FB | The voltage feedback from auxiliary winding | | |
| 3 | 3 | VCC | This pin receives rectified voltage from the auxiliary winding of the transformer | | |
| 4 | 4 | CS | Current sense for primary side of transformer | | |
| 5,6 | 5,6 | С | This pin is connected with an internal power BJT's collector | | |
| | 7 | NC | Not connected | | |
| 7 | 8 | GND | This pin is the signal reference ground | | |



AP3968/69/70/70S

Functional Block Diagram



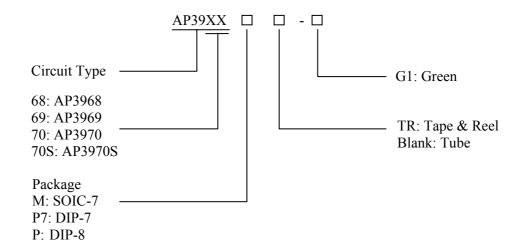
A (B) A for SOIC-7/DIP-7 B for DIP-8

Figure 3. Functional Block Diagram of AP3968/69/70/70S



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Ordering Information



| Package | Temperature Range | Part Number | Marking ID | Packing Type | |
|---------|----------------------|--------------|--------------|--------------|--|
| gord 2 | -40 to 85°C | AP3968M-G1 | AP3968M-G1 | Tube | |
| SOIC-7 | | AP3968MTR-G1 | AP3968M-G1 | Tape & Reel | |
| | | AP3969P7-G1 | AP3969P7-G1 | Tube | |
| DIP-7 | | AP3970P7-G1 | AP3970P7-G1 | Tube | |
| | | AP3970SP7-G1 | AP3970SP7-G1 | Tube | |
| DIP-8 | | AP3969P-G1 | AP3969P-G1 | Tube | |
| | | AP3970P-G1 | AP3970P-G1 | Tube | |
| | | AP3970SP-G1 | AP3970SP-G1 | Tube | |

BCD Semiconductor's Pb-free products, as designated with "G1" suffix in the part number, are RoHS compliant and green.



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Absolute Maximum Ratings (Note 2)

| Parameter | Symbol | Value | | Unit |
|--------------------------------------|------------------|------------|-----|------|
| Supply Voltage | V_{CC} | -0.3 to 22 | | V |
| FB Input Voltage | V_{FB} | -1 to 10 | | V |
| Collector-emitter Voltage | V_{CBO} | 700 | | V |
| | | AP3968/69 | 1.5 | |
| Collector DC Current | | AP3970 | 4 | A |
| | | AP3970S | 3.2 | |
| Operating Junction Temperature | T_{J} | 150 | | °C |
| Storage Temperature | T_{STG} | -65 to 150 | | °C |
| Lead Temperature (Soldering, 10 sec) | T_{LEAD} | 300 | | °C |
| ESD (Machine Model) | | 200 | | V |
| ESD (Human Body Model) | | 2000 | | V |

Note 2: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.

Recommended Operating Conditions

| Parameter | Symbol | Min | Max | Unit |
|-----------------------------|-----------|-----|-----|------|
| Supply Voltage | V_{CC} | | 22 | V |
| Operating Temperature Range | T_{OP} | -40 | 85 | °C |
| Maximum Operating Frequency | f_{MAX} | | 60 | kHz |



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Electrical Characteristics

V_{CC}=15V, T_J=25°C, unless otherwise specified.

| Parameter | Symbol | Conditions | Min | Тур | Max | Unit |
|---|----------------------|--|------|-----|------|------|
| UVLO Section | | | | | • | |
| Turn-on Voltage | V _{ON} | | 13 | 15 | 17 | V |
| Turn-off Voltage | V_{OFF} | No drive Current | 4.5 | 5.3 | 6.3 | V |
| Standby Current Section | | | | | • | |
| Start-up Current | I_{ST} | V _{CC} =V _{ON} -0.5V | | 0.2 | 0.6 | A |
| Operating Current | I_{CC} | | 320 | 435 | 550 | μΑ |
| Feedback Input Section | | | | | • | |
| FB Input Current | I_{FB} | V _{FB} =4V | 1.5 | 3.5 | 5.5 | μΑ |
| FB Threshold Voltage | V_{FB} | | 4.23 | 4.3 | 4.37 | V |
| Power Transistor Section | | | | | | |
| Collector-emitter Saturation Voltage | V _{CE(SAT)} | AP3968/9: I _C =0.5A AP3970/70S: I _C =1A | | | 0.3 | V |
| DC Current Gain | $h_{ m FE}$ | AP3968/69 | 14 | 17 | | |
| De current dani | | AP3970/70S | 17 | 26 | | |
| Leakage Current | I_{CEO} | | | | 60 | nA |
| Over Temperature Protect | tion | • | • | | • | |
| Shutdown Temperature | T_{SHDN} | Surface temperature | 125 | 160 | | °C |
| Temperature Hysteresis | | | | 40 | | °C |

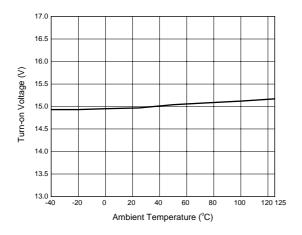
Thermal Impedance

| Parameter | Symbol | Va | Unit | |
|---------------------|------------------|---------|------|------|
| | $	heta_{ m JA}$ | AP3968 | 80 | |
| Junction to Ambient | | AP3969 | 60 | |
| Junction to Amolent | | AP3970 | 45 | |
| | | AP3970S | 50 | °C/W |
| | $\theta_{ m JC}$ | AP3968 | 40 | C/ W |
| Junction to Case | | AP3969 | 30 | |
| Junction to Case | | AP3970 | 22 | |
| | | AP3970S | 26 | |



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Typical Performance Characteristics



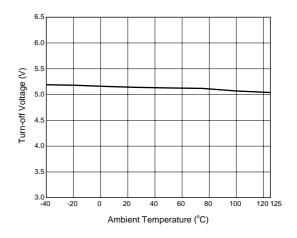


Figure 4. Turn-on Voltage vs. Ambient Temperature

Figure 5. Turn-off Voltage vs. Ambient Temperature

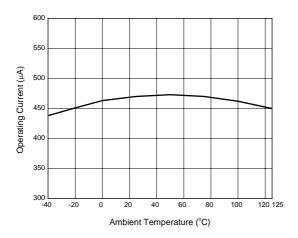


Figure 6. Operating Current vs. Ambient Temperature



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Operation Description

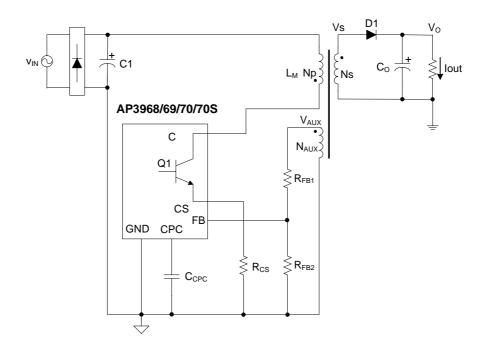


Figure 7. Simplified Flyback Converter Controlled by AP3968/69/70/70S

Figure 7 illustrates a simplified flyback converter controlled by AP3968/69/70/70S.

Constant Primary Peak Current

The primary current Ip(t) is sensed by a current sense resistor R_{CS} as shown in Figure 7.

The current rises up linearly at a rate of:

$$\frac{dip(t)}{dt} = \frac{vg(t)}{L_{M}}....(1)$$
See equation 2

Figure 8. Primary Current Waveform

As illustrated in Figure 8, when the current Ip(t) rises up to Ipk, the switch Q1 turns off. The constant peak current is given by:

$$Ipk = \frac{Vcs}{Rcs} \dots (2)$$

The energy stored in the magnetizing inductance L_{M} each cycle is therefore:

$$Eg = \frac{1}{2} \cdot L_{M} \cdot Ipk^{2} \cdot \dots (3)$$

So the power transferring from input to output is given by:

$$P = \frac{1}{2} \cdot L_{M} \cdot Ipk^{2} \cdot f_{SW} \cdot \dots (4)$$

Where f_{SW} is the switching frequency. When the peak current Ipk is constant, the output power depends on the switching frequency f_{SW} .

Constant Voltage Operation

The AP3968/69/70/70S captures the auxiliary winding feedback voltage at FB pin and operates in constant-voltage (CV) mode to regulate the output



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voltage. Assuming the secondary winding is master, the auxiliary winding is slave during the D1 on-time. The auxiliary voltage is given by:

$$V_{AUX} = \frac{N_{AUX}}{N_S} \cdot (V_0 + V_d) \cdot \dots (5)$$

Where V_d is the diode forward drop voltage, N_{AUX} is the turns of auxiliary winding, and N_S is the turns of secondary winding.

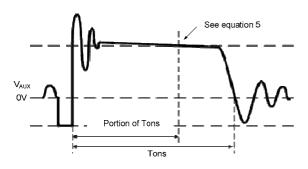


Figure 9. Auxiliary Voltage Waveform

The output voltage is different from the secondary voltage in a diode forward drop voltage V_d which depends on the current. If the secondary voltage is always detected at a constant secondary current, the difference between the output voltage and the secondary voltage will be a fixed V_d . The voltage detection point is portion of Tons after D1 is turned on. The CV loop control function of AP3968/69/70/70S then generates a D1 off-time to regulate the output voltage.

Constant Current Operation

The AP3968/69/70/70S is designed to work in constant current (CC) mode. Figure 10 shows the secondary current waveforms.

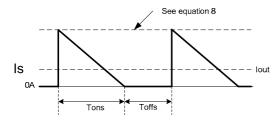


Figure 10. Secondary Current Waveform

In CC operation, the CC loop control function of AP3968/69/70/70S will keep a fixed proportion between D1 on-time Tons and D1 off-time Toffs by

discharging or charging the built-in capacitance connected. This fixed proportion is

$$\frac{\text{Tons}}{\text{Toffs}} = \frac{4}{3} \dots (6)$$

The relation between the output constant-current and secondary peak current Ipks is given by:

$$Iout = \frac{1}{2} \cdot Ipks \cdot \frac{Tons}{Tons + Toffs} \dots (7)$$

At the instant of D1 turn-on, the primary current transfers to the secondary at an amplitude of:

$$Ipks = \frac{N_p}{N_s} \cdot Ipk \dots (8)$$

Thus the output constant current is given by:

$$Iout = \frac{2}{7} \cdot \frac{N_p}{N_s} \cdot Ipk \dots (9)$$

Leading Edge Blanking (LEB)

When the power switch is turned on, a turn-on spike on the output pulse rising edge will occur on the sense-resistor. To avoid false termination of the switching pulse, a typical 500ns leading edge blanking is built in. During this blanking period, the current sense comparator is disabled and the gate driver can not be switched off.

The built-in LEB in AP3968/69/70/70S has shorter delay time from current sense terminal to output pulse than those IC solutions adopting external RC filter as LEB.

Built-in Cable Compensation

The AP3968/69/70/70S has built-in fixed voltage of 0.35V typical to compensate the drop of output cable when the load is changed from zero to full load. A typical $0.01\mu F$ external capacitor connected to the CPC pin is used to smooth voltage signal for cable compensation.

Over Temperature Protection

The AP3968/69/70/70S has internal thermal sensing circuit to shut down the PFM driver output when the die temperature reaches 160°C typical. When the die temperature drops about 40°C, the IC will recover automatically to normal operation.



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Typical Application

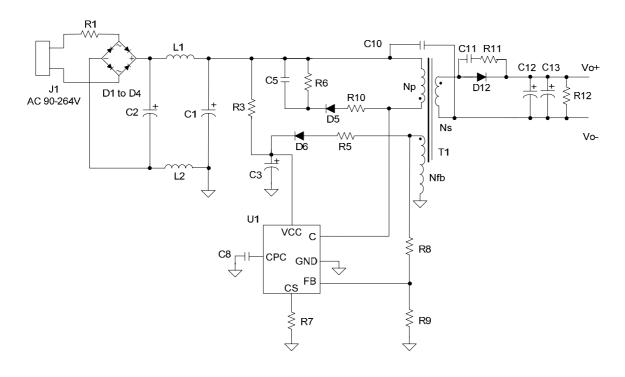


Figure 11. Typical Application of AP3969 (9V/800mA)

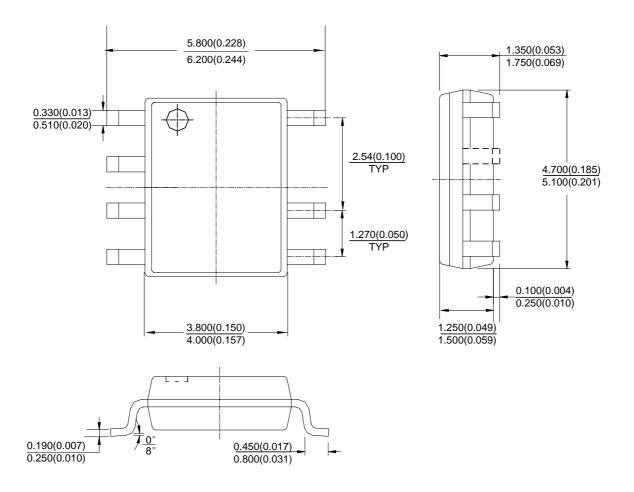
| Item | Description | QTY | Item | Description | QTY |
|----------|------------------------------|-----|------|---------------------------------|-----|
| C1 | 10.0μF/400V, electrolytic | 1 | U1 | AP3969 | 1 |
| C2 | 4.7μF/400V, electrolytic | 1 | R1 | 11Ω, 2W | 1 |
| C3 | 3.3μF/50V, electrolytic | 1 | R3 | $3.3M\Omega/0.25W$ | 1 |
| C5 | 1nF/1kV, ceramic | 1 | R5 | 3.9Ω , 0805 | 1 |
| C8 | 0.01µF, 0805 | 1 | R6 | 150KΩ, 1206 | 1 |
| C10 | 1nF/250Vac, Y1 capacitor | 1 | R7 | 1Ω, 1206 | 1 |
| C11 | 1nF, 0805 | 1 | R8 | 20KΩ, 0805 | 1 |
| C12, C13 | 470μF/16V | 2 | R9 | 13ΚΩ, 0805 | 1 |
| D1 to D6 | 1N4007, rectifier diode | 6 | R10 | $360\Omega, 0805$ | 1 |
| D12 | SB3100 | 1 | R11 | $27\Omega, 0805$ | 1 |
| L1 | 470μH, inductor | 1 | R12 | 1.2kΩ, 0805 | 1 |
| L2 | Bead, 0805 | 1 | T1 | EE16 core, PC40, transformer | 1 |



AP3968/69/70/70S

Mechanical Dimensions

SOIC-7 Unit: mm(inch)



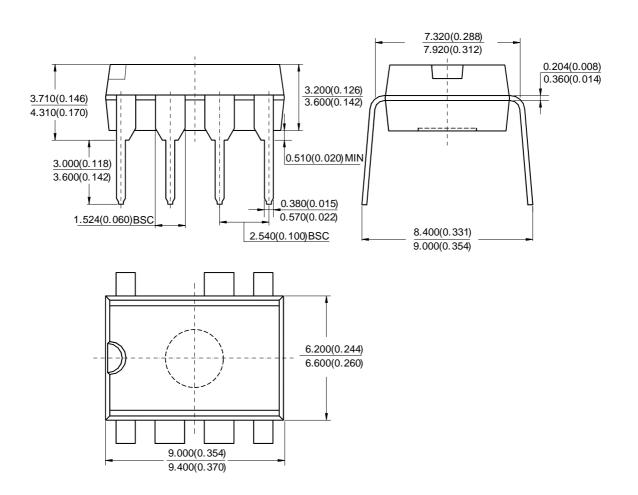
Note: Eject hole, oriented hole and mold mark is optional.



AP3968/69/70/70S

Mechanical Dimensions (Continued)

DIP-7 Unit: mm(inch)



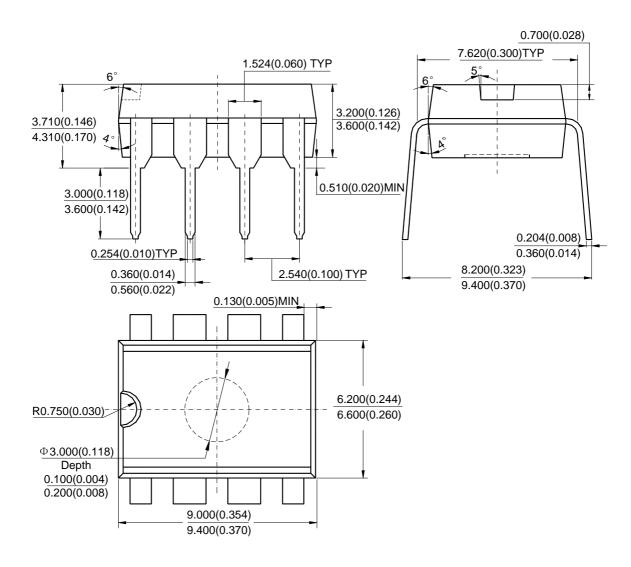
Note: Eject hole, oriented hole and mold mark is optional



AP3968/69/70/70S

Mechanical Dimensions (Continued)

DIP-8 Unit: mm(inch)



Note: Eject hole, oriented hole and mold mark is optional.





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MAIN SITE

- Headquarters

BCD Semiconductor Manufacturing Limited

No. 1600, Zi Xing Road, Shanghai ZiZhu Science-based Industrial Park, 200241, China Tel: +86-21-24162266, Fax: +86-21-24162277

REGIONAL SALES OFFICE

Shenzhen Office

Shanghai SIM-BCD Semiconductor Manufacturing Co., Ltd., Shenzhen Office Unit A Room 1203, Skyworth Bldg., Gaoxin Ave.1.S., Nanshan District, Shenzhen, China

China Tel: +86-755-8826 7951 Fax: +86-755-8826 7865 - Wafer Fab

Shanghai SIM-BCD Semiconductor Manufacturing Co., Ltd. 800 Yi Shan Road, Shanghai 200233, China Tel: +86-21-6485 1491, Fax: +86-21-5450 0008

Taiwan Office

BCD Semiconductor (Taiwan) Company Limited 4F, 298-1, Rui Guang Road, Nei-Hu District, Taipei,

Taiwan Tel: +886-2-2656 2808 Fax: +886-2-2656 2806 USA Office BCD Semiconductor Corp. 30920 Huntwood Ave. Hayward, CA 94544, USA Te!:+1-510-324-2988 Fax:+1-510-324-2788